DUAL NAND SCHMITT TRIGGER!

S5413 N7413

\$5413-A,F,W • N7413-A,F

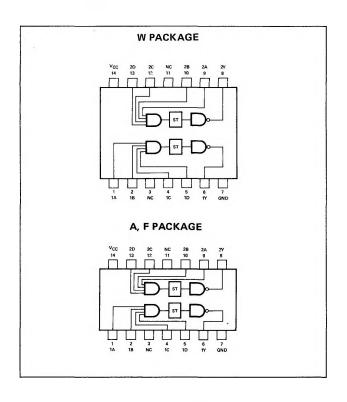
DIGITAL 54/74 TTL SERIES

DESCRIPTION

The 5413 and 7413 dual Schmitt triggers consist of two identical Schmitt-trigger circuits in monolithic integrated circuit form. Logically, each circuit functions as a four-input NAND gate, but because of the Schmitt action, the gate has different input threshold levels for positive- and negative-going signals. The hysteresis, or backlash, which is the difference between the two threshold levels, is typically 800mV.

An important design feature is the built-in temperature compensation which ensures very high stability of the threshold levels and the hysteresis over a very wide temperature range. Typically, the hysteresis changes by 3% over the temperature range of -55° C to 125° C and the upper threshold changes by 1% over the same range. The 5413/7413 can be triggered from the slowest of input ramps and still give clean, jitter-free output signals. It can not be triggered from straight dc levels.

These circuits are fully compatible with most other TTL, DTL, or MSI circuits. The 5413 is characterized for operation over the full military temperature range of -55° C to 125° C; the 7413 is characterized for operation from 0° C to 70° C.



RECOMMENDED OPERATING CONDITIONS

	5413 7413			UNIT			
	MIN	NOM	MAX	MIN	NOM	MAX	ONT
	4.5	5	5.5	4.75	5	5.25	V
High Logic Level Low Logic Level			20 10			20 10	
je, T _A	-55	0	125	0	25	70	°c
	N	No Restriction		No Restriction			
	High Logic Level Low Logic Level je, T _A	High Logic Level Low Logic Level je, T _A -55	High Logic Level Low Logic Level pe, T _A 4.5 5 4.5 5 0	High Logic Level 20 Low Logic Level 10 pe, T _A -55 0 125	High Logic Level 20 10 10 125 0	High Logic Level 20 20 10 10 10 10 10 15 15 15 15 15 15 15 15 15 15 15 15 15	High Logic Level 20 20 20 Low Logic Level 10 10 10 10 10 10 10 10 10 10 10 10 10

ELECTRICAL CHARACTERISTICS (over recommended operating free-air temperature range unless otherwise noted)

PARAMETER		TEST CONDITIONS*		MIN	TYP**	MAX	UNIT
v _{T+}	Positive-going threshold voltage	V _{CC} = 5V		1.5	1.7	2	V
VT-	Negative-going threshold voltage	V _{CC} = 5V		0.6	0 .9	1.1	
$V_{T+}-V_{T-}$	Hysteresis	V _{CC} = 5V		0.4	0 .8		V
VI	Input clamp voltage	V _{CC} = MIN,	$I_1 = -12mA$			-1.5	V
Vон	High-level output voltage	V _{CC} = MIN, I _{OH} = -800μA	V _I = 0.6V,	2.4	3.3		v
V _{OL}	Low-level output voltage	V _{CC} = MIN, I _{OL} = 16mA	V _I = 2V,		0.22	0.4	v
I _{T+}	Input current at positive-going threshold	V _{CC} = 5V,	V _I = V _{T+}		-0.65		mA
IT-	Input current at negative-going threshold	V _{CC} = 5V,	V1 = VT-		-0.85		mA
I _I	Input current at maximum input voltage	V _{CC} = MAX,	V ₁ = 5.5V			1	mA
Iн	High-level input current	$V_{CC} = MAX$,	V ₁ = 2.4V			40	μΑ
li <u>L</u>	Low-level input current	$V_{CC} = MAX$	V ₁ = 0.4V		-1	-1.6	m.A
los	Short-circuit output current [†]	VCC = MAX,	·	-18		-55	mA
ССН	Supply current, high-level output	V _{CC} = MAX,	V _I = 0		14	23	m/
ICCL	Supply current, low-level output	V _{CC} = MAX,	V ₁ = 4.5V		20	32	m <i>A</i>

SWITCHING CHARACTERISTICS, $V_{CC} = 5V$, $T_A = 25^{\circ}C$, N = 10

	PARAMETER	TEST	MIN	TYP	MAX	UNIT	
tPLH	Propagation delay time, low-to- high-level output	C _L = 15pF,	R _L = 400Ω		18	27	ns
^t PHL	Propagation delay time, high-to- low-level output	C _L = 15pF,	$R_L = 400\Omega$		15	22	ns

- For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable device type.
- * All typical values are at $V_{CC} = 5V$, $T_A = 25^{\circ}C$.
- † Not more than one output should be shorted at a time.

TYPICAL CHARACTERISTICS

